



#### 60V DUAL NPN LOW SATURATION TRANSISTOR IN SOT26

#### **Features**

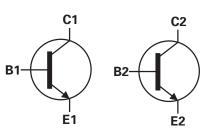
- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 1A high Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- $R_{CE(sat)} = 100 m\Omega$  for a Low Equivalent On-Resistance
- Low Saturation Voltage V<sub>CE(sat)</sub> < 250mV @ 1A</li>
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

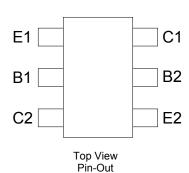
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.015 grams (approximate)







Device Symbol



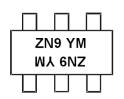
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS4160DS-7	ZN9	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

#### **Marking Information**



ZN9 = Product Type Marking Code YM = Date Code Marking Y = Year ex: A = 2013

M = Month ex: 9 = September

Date Code Key

Year	2013	20	014	2015	2	2016	2017		2018	2019		2020
Code	Α		В	С		D	E		F	G		Н
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### Absolute Maximum Ratings - Q1 & Q2 Common (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Collector Current	I <sub>CM</sub>	2	Α
Base current	I <sub>B</sub>	300	mA
Peak Pulse Base current	I <sub>BM</sub>	1	Α

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Characteristic			Unit	
	(Notes 5 & 9)		0.7 5.6		
	(Notes 6 & 9)		0.9 7.2		
Power Dissipation Linear Derating Factor	(Notes 6 & 10)	P <sub>D</sub>	1.1 8.8	W mW/°C	
	(Notes 7 & 9)		1.1 8.8		
	(Notes 8 & 9)		1.7 13.6		
	(Notes 5 & 9)		179		
	(Notes 6 & 9)		139		
Thermal Resistance, Junction to Ambient	(Notes 6 & 10)	$R_{ hetaJA}$	113	0000	
	(Notes 7 & 9)		113	°C/W	
	(Notes 8 & 9)		73		
Thermal Resistance, Junction to Lead	(Note 11)	$R_{ heta JL}$	96		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

#### ESD Ratings (Note 12)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

  6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.

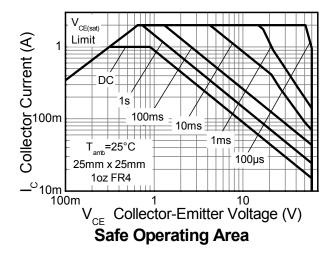
  7. Same as note (5), except the device is mounted on 50mm x 50mm 2oz copper.

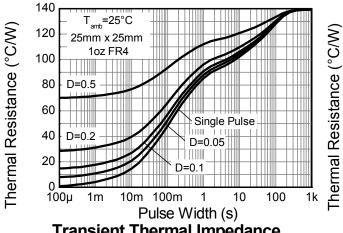
  8. Same as note (7), except the device is measured at t < 5 seconds.

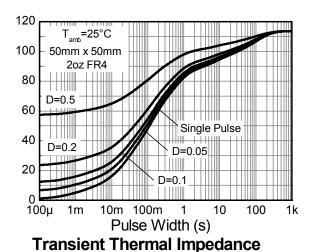
- 9. One active die operating with the collector attached to the heatsink.
- 10. Two active dice running at equal power with heatsink split 50% to each collector.
- 11. Thermal resistance from junction to solder-point (at the end of the collector lead).
- 12. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



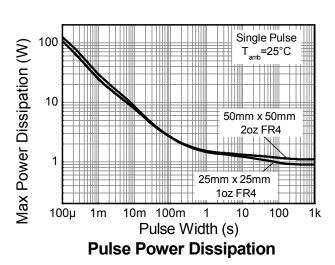
## **Thermal Characteristics and Derating Information**

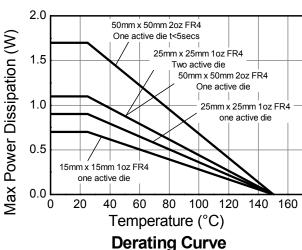






Transient Thermal Impedance







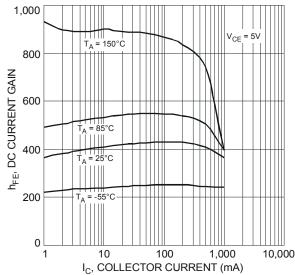
## Electrical Characteristics - Q1 & Q2 common (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	80	_	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 13)	BV <sub>CEO</sub>	60	_	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	5	_	_	V	I <sub>E</sub> = 100μA
Collector-Base Cutoff Current	1	_	_	100	nA	$V_{CB} = 60V, I_{E} = 0A$
Collector-Base Cutoff Current	I <sub>CBO</sub>	_	_	50	μΑ	$V_{CB} = 60V$ , $I_{E} = 0A$ , $T_{J} = +150$ °C
Collector-Emitter Cutoff Current	I <sub>CES</sub>	_	_	100	nA	$V_{CES} = 60V$ , $V_{BE} = 0V$
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 5V$ , $I_C = 0A$
		250	380	_		I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
DC Current Gain (Note 13)	$h_{FE}$	200	420	_	_	$I_C = 500 \text{mA}, V_{CE} = 5 \text{V}$
		100	380	—		$I_C = 1A$ , $V_{CE} = 5V$
		_	60	110		$I_C = 100 \text{mA}, I_B = 1 \text{mA}$
Collector-Emitter Saturation Voltage (Note 13)	$V_{CE(sat)}$	_	70	140	mV	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$
		_	100	250		I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Equivalent On-Resistance	R <sub>CE(sat)</sub>	_	100	250	mΩ	I <sub>C</sub> = 1A, I <sub>B</sub> = 100mA
Base-Emitter Saturation Voltage (Note 13)	$V_{BE(sat)}$	_	940	1100	mV	$I_C = 1A$ , $I_B = 50mA$
Base-Emitter Turn-On Voltage (Note 13)	$V_{BE(on)}$	_	780	900	mV	I <sub>C</sub> = 1A, V <sub>CE</sub> = 5V
Output Capacitance	$C_{obo}$	_	5.5	10	pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	f <sub>T</sub>	150	220	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA f = 100MHz
Turn-On Time	t <sub>on</sub>	_	63	_	ns	
Delay Time	t <sub>d</sub>	_	33	_	ns	
Rise Time	t <sub>r</sub>	_	30	_	ns	$V_{CC} = 10V, I_C = 0.5A$
Turn-Off Time	$t_{off}$	_	420	_	ns	I <sub>B1</sub> = -I <sub>B2</sub> = 25mA
Storage Time	t <sub>s</sub>	_	380	_	ns	_
Fall Time	t <sub>f</sub>		40	_	ns	

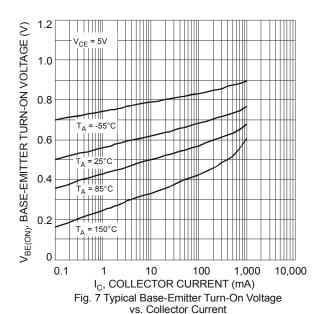
Notes: 13. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%

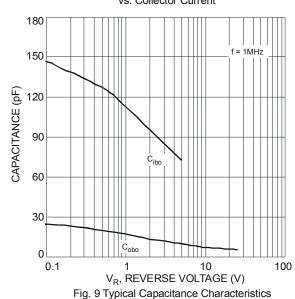


#### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



I<sub>C</sub>, COLLECTOR CURRENT (mA)
Fig. 5 Typical DC Current Gain vs. Collector Current





 $I_C/I_B = 10$ V<sub>CE(SAT)</sub>, COLLECTOR-EMITTER SATURATION VOLTAGE (V) 0.01 -55°C 0.001 0.1 100 1,000 10,000 10  $\rm I_{\rm C},$  COLLECTOR CURRENT (mA)

Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

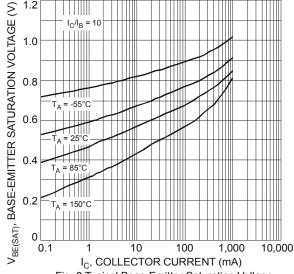
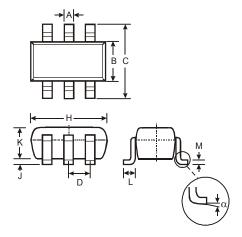


Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current



## **Package Outline Dimensions**

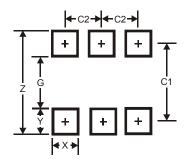
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT26					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_	_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
M	0.10	0.20	0.15			
α	0°	8°	_			
All D	imensi	ons in	mm			

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95



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